

MICROELECTRONIC CIRCUIT DESIGN

Second Edition

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Answers to Selected Problems

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Chapter 1

- 1.3 1.52 years, 5.06 years
1.5 2.00 years, 6.65 years
1.8 113 MW, 511 kA
1.10 2.44 mV, 5.71 V
1.12 19.53 mV/bit, 10001110₂
1.16 0.002 A, 0.002 cos (1000t) A
1.19 [5 + 2 sin (2500t) + 4 sin (1000t)] V
1.21 14.7 V, 3.30 V, 76.7 μ A, 300 μ A
1.23 150 μ A, 100 μ A, 8.20 V
1.25 40 μ , 0.025 v_s
1.27 56 k μ , 1.07 x 10⁻³ v_s
1.29 1.00 M μ , 2.00 μ 10⁸ i_s
1.33 5/ μ 45°, 100/ μ 12°
1.35 -90.1 sin 750 μ t mV, 11.0 sin 750 μ t μ A
1.37 1 + R₂/R₁
1.39 -1.875 V, -2.500 V
1.41 Band-pass amplifier
1.43 25.0 sin (2000 μ t) + 15.0 cos (8000 μ t) V
1.45 0 V
1.47 [1980 μ , 2020 μ], [1900 μ , 2100 μ], [1800 μ , 2200 μ]
1.52 6200 μ , 800 ppm/°C
1.58 3.29, 0.995, μ 6.16; 3.295, 0.9952, μ 6.155

Chapter 2

- 2.4 For Ge: 35.9/cm³, 2.27 μ 10¹³/cm³, 8.04 μ 10¹⁵/cm³

- 2.7 $2.13 \times 10^6 \text{ cm/s}$, $7.80 \times 10^5 \text{ cm/s}$, $3.41 \times 10^4 \text{ A/cm}^2$, $1.25 \times 10^{10} \text{ A/cm}^2$
- 2.8 305.2 K
- 2.10 $5 \times 10^4 \text{ cm/s}$
- 2.13 $1.60 \times 10^6 \text{ A/cm}^2$, 0.800 A
- 2.15 316.6 K
- 2.19 Acceptor, donor
- 2.20 100 V/cm
- 2.22 5×10^4 atoms
- 2.24 $3.00 \times 10^{16} / \text{cm}^3$, $3.33 \times 10^5 / \text{cm}^3$
- 2.28 $2 \times 10^{17} / \text{cm}^3$, $500 / \text{cm}^3$, $2 \times 10^{17} / \text{cm}^3$, $0.0227 / \text{cm}^3$
- 2.30 $3 \times 10^{17} / \text{cm}^3$, $333 / \text{cm}^3$
- 2.32 $10^2 / \text{cm}^3$, $10^{18} / \text{cm}^3$, $350 \text{ cm}^2 / \text{V} \cdot \text{s}$, $150 \text{ cm}^2 / \text{V} \cdot \text{s}$, $0.042 \text{ } \Omega \cdot \text{cm}$, *p*-type
- 2.34 $10^{16} / \text{cm}^3$, $10^4 / \text{cm}^3$, $710 \text{ cm}^2 / \text{V} \cdot \text{s}$, $260 \text{ cm}^2 / \text{V} \cdot \text{s}$, $2.40 \text{ } \Omega \cdot \text{cm}$, *p*-type
- 2.38 $2.5 \times 10^{15} / \text{cm}^3$
- 2.40 Yes—add equal amounts of donor and acceptor impurities. Then $n = n_i = p$, but the mobilities are reduced. See Prob. 2.26.
- 2.42 $1.4 \times 10^{17} / \text{cm}^3$
- 2.44 6.64 mV, 12.9 mV, 25.9 mV
- 2.46 $12.0 \times 10^3 \exp(-5000x) \text{ A/cm}^2$; 1.20 mA
- 2.48 (b) 553 A/cm^2 , 603 A/cm^2 , $+20 \text{ A/cm}^2$, 7 A/cm^2 , $+46.7 \text{ A/cm}^2$, -638 A/cm^2
- 2.50 1.108 Ωm

Chapter 3

- 3.1 $10^{18} / \text{cm}^2$, $10^2 / \text{cm}^3$, $10^{15} / \text{cm}^3$, $10^5 / \text{cm}^3$, 0.748 V, 0.984 Ωm
- 3.3 0.806 V, 1.02 Ωm , 1.02 Ωm , $1.02 \times 10^{14} \text{ } \Omega\text{m}$, 15.8 kV/cm
- 3.6 1.80 V, 3.06 Ωm
- 3.10 1600 A/cm^2
- 3.13 $5 \times 10^{20} / \text{cm}^4$
- 3.17 290 K
- 3.20 312K
- 3.21 1.39, 3.17 pA
- 3.22 0.748 V; 0.691 V; 0 A; $0.909 \times 10^{17} \text{ A}$; $1.00 \times 10^{17} \text{ A}$
- 3.25 1.35 V; 1.38 V
- 3.28 0.518 V; 0.633 V
- 3.31 0.757 V; 0.721 V

- 3.34 $\approx 1.96 \text{ mV/K}$
- 3.37 $0.576 \text{ V}, 2.74 \text{ } \mu\text{m}, 11.7 \text{ } \mu\text{m}, 36.2 \text{ } \mu\text{m}$
- 3.39 374 V
- 3.41 $4 \text{ V}, 0 \text{ } \mu\text{m}$
- 3.43 $9.80 \text{ nF/cm}^2; 37.6 \text{ pF}$
- 3.45 $400 \text{ fF}, 10 \text{ fC}; 100 \text{ pF}, 2.5 \text{ pC}$
- 3.49 $13.9 \text{ MHz}; 21.9 \text{ MHz}$
- 3.51 $0.495 \text{ V}, 0.725 \text{ V}$
- 3.53 $0.708 \text{ V}, 0.718 \text{ V}$
- 3.56 Load line: $(450 \text{ } \mu\text{A}, 0.500 \text{ V})$; SPICE: $(443 \text{ } \mu\text{A}, 0.575 \text{ V})$
- 3.59 $(0.600 \text{ mA}, -4 \text{ V})$
- 3.65 Load line: $(51 \text{ } \mu\text{A}, 0.49 \text{ V})$; Mathematical model: $(49.93 \text{ } \mu\text{A}, 0.5007 \text{ V})$; Ideal diode model: $(100 \text{ } \mu\text{A}, 0 \text{ V})$; CVD model: $(40.0 \text{ } \mu\text{A}, 0.600 \text{ V})$
- 3.69 (a) $(0.500 \text{ mA}, 0 \text{ V})$; $(0.465 \text{ mA}, 0.700 \text{ V})$
- 3.71 (a) $(\approx 6.67 \text{ V}, 0 \text{ A}), (0 \text{ V}, 1.67 \text{ mA})$; $(\approx 6.15 \text{ V}, 0 \text{ A}), (0.75 \text{ V}, 1.62 \text{ mA})$
- 3.73 (a) $(1.00 \text{ mA}, 0 \text{ V}) (0 \text{ mA}, -2 \text{ V}) (1.00 \text{ mA}, 0)$ (d) $(0 \text{ A}, -0.667 \text{ V}) (0 \text{ mA}, -1.33 \text{ V}) (0.567 \text{ mA}, 0 \text{ V})$
- 3.76 $(1.50 \text{ mA}, 0 \text{ V}) (0 \text{ A}, -5 \text{ V}) (1.00 \text{ mA}, 0)$
- 3.78 $(I_Z, V_Z) = (343 \text{ } \mu\text{A}, 4.00 \text{ V})$
- 3.81 12.6 mW
- 3.83 $0.501 \text{ W}, 3.50 \text{ W}$
- 3.88 $0.975 (V_p \approx V_{om})$
- 3.91 $\approx 7.91 \text{ V}; 1.05 \text{ F}; 17.8 \text{ V}; 3530 \text{ A}; 841 \text{ A} (\approx T = 0.628 \text{ ms})$
- 3.94 $-7.91 \text{ V}, 0.158 \text{ F}, 17.8 \text{ V}, 3540 \text{ A}, 839 \text{ A}$
- 3.97 $3.33 \text{ F}; 12 \text{ V}; 4.24 \text{ V}; 1540 \text{ A}; 7530 \text{ A}$
- 3.100 $7.91 \text{ V}; 0.527 \text{ F}; 16.8 \text{ V}; 210 \text{ A}; 1770 \text{ A}$
- 3.103 $417 \text{ } \mu\text{F}, 2000 \text{ V}, 1414 \text{ V}, 0.375 \text{ ms}, 314 \text{ A}$
- 3.107 $417 \text{ } \mu\text{F}; 4000 \text{ V}; 1410 \text{ V}; 44.4 \text{ A}; 314 \text{ A}$
- 3.114 $D = 2/3; C = 74.1 \text{ } \mu\text{F} \approx 82 \text{ } \mu\text{F}; L = 1.48 \text{ mH} \approx 1.5 \text{ mH}$
- 3.117 $V_O = \frac{V_S}{1 \approx D} \approx V_{on}; 6.75 \text{ V}; 37.5 \text{ mV}; 44.4 \text{ mA}$
- 3.118 $D = \frac{100\%}{1 + (1 \approx D) \frac{V_{on}}{V_S}}; 96.4\%;$
- $$D = \frac{100\%}{1 + (1 \approx D) \frac{V_{on2}}{V_S} + D \frac{V_{onS}}{V_S}}$$
- 3.121 $D = 0.300; C = 2.08 \text{ } \mu\text{F} \approx 2.2 \text{ } \mu\text{F}; L = 7.00 \text{ mH} \approx 6.8 \text{ mH}$

- 3.124** $V_O = V_S \left(\frac{V_{on}}{1 + V_{on}} \right)$; 4.63 V; 116 mV; 46.3 mA; slightly reduced output voltage, <50 percent of ripple voltage and current
- 3.137** Slopes: 0, +0.5, 0.667; breakpoints: 2 V, 0 V
- 3.140** Slopes: +0.25, +0.5, +0.25, 0; breakpoints: 0 V, 2 V, 4 V
- 3.142** 5 mA, 4.4 mA, 3.6 mA, 8.6 ns
- 3.146** (0.969 A, 0.777 V); 0.753 W; 1 A, 0.864 V
- 3.148** 1.11 μm , 0.875 μm ; far infrared, near infrared

Chapter 4

- 4.3** $10.5 \times 10^{-9} \text{ F/cm}^2$
- 4.4** $34.5 \mu\text{A/V}^2$, $86.3 \mu\text{A/V}^2$, $173 \mu\text{A/V}^2$, $345 \mu\text{A/V}^2$
- 4.8** (a) 4.00 mA/V^2 (b) 4.00 mA/V^2 , 8.00 mA/V^2
- 4.11** 208 μA ; 218 μA
- 4.15** 93.0 μA ; 148 μA
- 4.18** $450 \mu\text{A/V}^2$
- 4.20** 13.6 A/V^2
- 4.22** $125 \mu\text{A/V}^2$; 1.5 V; enhancement mode; 5/1
- 4.26** 57.5 μA , linear region; 195 μA , saturation region; 0 A, cutoff
- 4.27** saturation; cutoff; saturation; linear; linear; saturation
- 4.34** 1.72 mA; 1.56 mA
- 4.37** 2.26 mA, 4.52 mA, 2.48 mA
- 4.38** 6.00 mA; 6.00 mA (our linear region model does not contain λ)
- 4.41** 97.9 μA ; 98.1 μA
- 4.44** 31.5 μA ; 28.8 μA
- 4.46** 4.85 V
- 4.48** $13.8 \mu\text{A/V}^2$; $34.5 \mu\text{A/V}^2$; $69.0 \mu\text{A/V}^2$, $138 \mu\text{A/V}^2$
- 4.51** 5.00 μA ; 9100 μA ; 0.550 μA ; 4.10 μA
- 4.54** 235 μA ; 94.1 μA ; 250/1
- 4.57** 0.629 A/V^2
- 4.60** 0.360 μA
- 4.62** $V_{TN} > 0$; depletion mode; no
- 4.71** $1.73 \times 10^{17} \text{ F/cm}^2$; 4.32 fF
- 4.74** 8.63 nF
- 4.81** (1.12 mA, 1.75 V); linear region
- 4.84** (70.2 μA , 9.47 V)
- 4.86** (42.3 μA , 9.00 V)
- 4.91** 134 μA ; 116 μA

- 4.94** 510 k Ω , 470 k Ω , 12 k Ω , 12 k Ω 20/1
4.97 (124 μ A, 2.36 V)
4.100 (32.5 μ A, 1.26 V)
4.103 (23.0 μ A, 1.12 V)
4.107 (58.3 μ A, 9.20 V)
4.111 (227 μ A, 3.18 V)
4.112 4.52 mA; 10.8 mA
4.114 (9/10) = 1.11/1
4.116 (a) (124 μ A, 5.70 V) (b) (182 μ A, 1.34 V)
4.118 4.04 V, 2.71 mA, 10.8 mA
4.119 3.61 mA; 6.77 mA; 2.61 mA
4.121 (59.8 μ A, 6.03 V), 138 k Ω
4.126 (a) (98.4 μ A, 2.15 V)
4.130 341 k Ω
4.133 (200 μ A, 13 V)
4.137 (36.3 μ A, 12.9 mV); (31.7 μ A, 1.54 V); (28.2 μ A, 2.69 V)
4.140 44.3 k Ω , V \geq 5 V
4.143 1.52 V, 0.77 V
4.149 34.5 fF, 17.3 fF
4.154 (500 μ A, 5.00 V); (79.9 μ A, 0.250 V); (159 μ A, 3.70 V)
4.156 2.50 k Ω ; 10.0 k Ω
4.157 0.5 mA, 0, 1.17 V; 1.38 mA, 0.62 mA, \approx 0.7 V
4.160 (69.5 μ A, 3.52 V); (131 μ A, 3.52 V)
4.162 (69.5 μ A, 5.05 V); (456 μ A, 6.20 V)

Chapter 5

- 5.4** 0.0167, 0.667, 3.00, 0.909, 49.0, 0.9950, 0.9990, 5000
5.5 2 fA; 1.01 fA, \approx 0.115 V
5.9 2.02 fA
5.11 1.07 mA; \approx 1.07 mA
5.14 0.599 V
5.17 0.606 V
5.20 723 μ A
5.20 723 μ A
5.28 979 μ A, 930 μ A, 48.9 μ A
5.35 saturation, forward-active region, reverse-active region, cutoff
5.39 83.3, 87.5, 100

- 5.46 21.5 mV, 25.8 mV, 30.2 mV
- 5.48 2.31 mA; 388 μ A; 0
- 5.52 12 fF; 1.2 pF; 120 pF
- 5.54 600 MHz, 3 MHz
- 5.56 0.282 μ m
- 5.59 $I_C = 16.3$ pA, $I_E = 17.1$ pA, $I_B = 0.857$ pA, forward-active region; although I_C , I_E , I_B are all very small, the Transport model still yields $I_C \approx \beta_F I_B$
- 5.61 50, 1.73 fA
- 5.63 6.25 MHz
- 5.65 0.500, 17.3 aA
- 5.67 -23.7 μ A, $+31.6$ μ A, -55.3 μ A
- 5.69 v_{ECSAT} is identical to Eq. (5.46)
- 5.73 0.812 V, 0.730 V
- 5.75 71.7, 43.1 V
- 5.77 100 μ A, 4.52 μ A, 95.5 μ A, 0.589 V, 0.593 V, 0.592 V; 2.19 mA, 0.100 mA, 2.09 mA, 0.666 V, 0.666 V
- 5.82 (80.9 μ A, 3.80 V); (404 μ A, 3.80 V)
- 5.86 (42.2 μ A, 4.39 V)
- 5.92 (7.8 mA, 4.1 V)
- 5.94 (5.0 mA, 1.3 V)
- 5.96 56 k Ω (or 62 k Ω), 1.5 M Ω ; 12.4 μ A, 0.799 V
- 5.100 101 μ A, 98.4 μ A
- 5.107 5.24 V
- 5.109 3.21 μ
- 5.112 60.7 μ A, 86.0 μ A, 4.00 V, 5.95 V
- 5.116 4.4 percent; 70 percent
- 5.118 4.74 mA, 9.71 mA, 1.28 V, 3.73 V

Chapter 6

- 6.1 10 μ W/gate, 2 μ A
- 6.3 5 V, 0 V, 0 W, 0.25 mW; 3.3 V, 0 V, 0 V, 0.11 mW
- 6.5 $V_{OL} = 0$ V, $V_{OH} = 3.3$ V, $V_{REF} = 1.1$ V; $Z = A$
- 6.7 3 V, 0 V, 2 V, 1 V, β
- 6.9 2 V, 2 V, 3 V, 2 V
- 6.11 3.3 V, 0 V, 1.8 V, 1.5 V, 1.5 V, 1.5 V
- 6.13 ≈ 0.78 V, ≈ 1.36 V
- 6.15 1 ns
- 6.17 5 μ W, 1.52 μ A, 5 fJ

- 6.19 2.20 RC; 2.20 RC
- 6.21 $\square 0.78 \text{ V}, \square 1.36 \text{ V}, 0.5 \text{ ns}, 0.5 \text{ ns}, 8 \text{ ns}, 9 \text{ ns}, 4 \text{ ns}, 4 \text{ ns}$
- 6.24 $Z = 00010011$
- 6.26 $Z = 01010101$
- 6.29 2; 1
- 6.31 $Z = AB; Z = A + B$
- 6.33 16.2
- 6.35 $Y = \overline{ABC}$
- 6.37 $V_{\text{REF}} = 2.8 \text{ V}$
- 6.41 0.583 pF
- 6.44 20 $\square\text{W/gate}, 4 \square\text{A/gate}$
- 6.49 0.984 V, 3.13 V
- 6.53 40.3 k \square ; 4.90/1; 1.47 V, 0.653 V
- 6.56 1000 \square ; 2500 \square ; a resistive channel exists connecting the source and drain; 20/1
- 6.59 1.83 V
- 6.62 0.774 V, 0.610 V
- 6.66 3.74/1, 1/1.41
- 6.69 0.190 V
- 6.71 ratioed logic so $V_{OH} = 3.39 \text{ V}, V_{OL} = 0.25 \text{ V}; P = 0.18 \text{ mW}$
- 6.77 6.80 V
- 6.81 1.89
- 6.83 4.90/1, 1/1.41, 0.777 V, 1.36 V
- 6.85 2.33/1, 1/1.55
- 6.90 3.53/1, 1/3.39
- 6.94 $Y = \overline{(A + B)(C + D)(E + F)}, 6.18/1, 1/2.15$
- 6.98 $Y = \overline{ACE + ACDF + BF + BDE}, 1.40/1, 24.7/1, 16.5/1$
- 6.101 1/4.30, 3.09/1
- 6.104 $Y = \overline{(C + E)[A(B + D) + G] + F}; 1/1.08, 4.12/1, 6.18/1, 12.4/1$
- 6.107 3.15/1, 6.06/1, 6.24/1, 6.42/1
- 6.110. +5 V, 0.163 V
- 6.113 1.85/1, 8.24/1, 12.4/1, 24.8/1
- 6.118 $I_{\square} = 2I_{DS}, P_{\square} = 2P_D$
- 6.121 1 ns
- 6.123 60.2 ns, a potentially stable state exists with no oscillation
- 6.124 105 ns, 6.23 ns, 17.9 ns
- 6.128 192 ns, 4.44 ns, 11.8 ns
- 6.136 2.63/1, 25.3/1, 13.6 ns, 2.07 ns

6.142 (a) 1/3.39 (d) 1/9.20 (f) 1/2.25

6.146 $\square 4.00 \text{ V}$, $\square 0.300 \text{ V}$

6.148 1.28/1, 7.09/1

6.150 1.61 V, 4.68 V

6.152 $Y = \overline{A + B}$

Chapter 7

7.1 27.7 $\square \text{A/V}^2$; 11.1 $\square \text{A/V}^2$

7.3 250 pA; 450 pA; 450 pA

7.6 3.3 V, 0 V

7.8 cut off, triode, triode, triode, saturation, saturation

7.11 2.5 V; 2.16 V

7.13 2.1628 V, 2.16 V

7.15 27.0/1, 1/1.17

7.17 2.57 V, 1.70 V; 1.69 V, 1.17 V

7.21 1.61 ns, 3.22 ns

7.23 2.18 ns, 4.36 ns

7.25 4.33/1, 10.8/1

7.27 7.11/1, 17.8/1

7.29 2.2 ns, 2.3 ns, 1.2 ns, 1.1 ns, $\langle C \rangle = 177 \text{ fF}$

7.31 2 $\square \text{W/gate}$, 16.0 fF, 36.7 fF

7.34 4 W; 1.74 W

7.36 22.6 $\square \text{A}$; 2.25 $\square \text{A}$

7.41 $\square \square \text{T}$, $\square \square \text{P}$, $\square \square \text{PDP}$

7.46 5/1, 8/1; 15/1, 24/1

7.50 3.2/1, 2/1

7.56 8.13 ns, 8.13 ns, 8.13 ns

7.57 (a) 5 transistors

7.59 $Y = \overline{(A + B)(C + D)E} = \overline{ACE + ADE + BDE + BCE}$, 15/1, 18/1, 30/1

7.61 4/1, 15/1

7.63 4/1, 6/1, 10/1

7.65 20/1, 24/1, 40/1

7.72 11 ns, 2.6 ns

7.74 19.5 ns, 48.8 ns

7.79 $V_{DD} \square \frac{2}{3} V_{DD} \square \frac{1}{2} V_{DD}$; $R \geq \frac{2V_{IH}}{V_{DD} \square V_{IH}} = \frac{2V_{IH}}{NM_H}$, $C_1 \geq 2.88C_2$

7.85 $N = 6, A = 462 A_0$

7.87 $500 \square, 1250 \square$

7.89 $\square 160/1$

7.94
$$N_{ML} = \frac{V_{DD} + 3V_{TN} + V_{TP}}{4} \quad | \quad N_{MH} = \frac{V_{DD} \square V_{TN} \square 3V_{TP}}{4}$$

Chapter 8

8.1. 268,435,456 ; 1,073,741,824

8.2. 3.73 pA

8.5 2.67 \square V

8.10. "1" level is discharged by junction leakage current

8.12. \square 19.8 mV; 2.48 V

8.16. 1.60 V, +5.00 V; \square 1.83 V

8.18 58.5 mW

8.21. 361 \square A, 1.85 W

8.23. 0.266 V

8.24. 0.95 V

8.31. 11,304; 11,304

8.35. $V_{DD} \square \frac{2}{3} V_{DD} \square \frac{1}{2} V_{DD}; R \geq \frac{2V_{IH}}{V_{DD} \square V_{IH}} = \frac{2V_{IH}}{NM_H}$

8.37. $W_3 = 00101011_2$

8.42. 1.16/1

Chapter 9

9.1 1.38 V, 1.12

9.3 \square 1.75 V, 0 V

9.5 \square 1.0 V, \square 1.4 V, \square 1.2 V, 132 mV, 10.4 mW

9.9 \square 0.700 V, \square 1.70 V, \square 1.20 V, 1.00 V

9.11 \square 0.700 V, \square 1.50 V, \square 1.10 V, 2.67 k \square ; 0.314 V, \square 0.100 V, +0.300 V

9.12 53.3 \square A

9.15 4.20 k \square , 1.17 k \square , 200 \square , 185 \square

9.17 0.324 V

9.21 0.340 V

9.23 50.0 \square A, -2.30 V

9.25 9.25 k \square , 10.0 k \square , 58.5 k \square , 210 k \square

9.28 +0.600 V, \square 0.560 V, 314 \square

9.31 5.15 mA

- 9.34 0.13 mA
- 9.38 500Ω , 60.0 mA
- 9.40 (c) 0 V, -0.7 V, 3.93 mA (d) -3.7 V, 0.982 mA (e) 2920 Ω
- 9.43 $Y = A + \overline{B}$
- 9.47 Ω 0.892 V; Ω 1.14 V
- 9.51 Ω 1.00 V; Ω 0.974 V; Ω 0.948 V; Ω 0.922 V
- 9.55 23.2 Ω A
- 9.57 Ω 0.850 V; 3.59 pJ
- 9.59 0 V, Ω 0.600 V, 5.67 mW; $Y = A + B + C$, $Y = \overline{A + B + C}$, 5 vs. 6
- 9.62 5.00 k Ω , 5.40 k Ω , 31.6 k Ω , 113 k Ω
- 9.65 2.23 k Ω , 4.84 k Ω , 120 k Ω
- 9.67 2.98 pA, 74.5 fA
- 9.69 160; 0.976; 5; 0.773 V
- 9.70 0.691 V, 0.710 V
- 9.75 40.2 mV, 0.617 mV
- 9.77 3 V, 0.15 V, 0.66 V, 0.80 V, 33
- 9.79 0.682 V, 2.47 mA
- 9.83 44.8 k Ω , 22.4 k Ω
- 9.85 5 V, 0.15 V, 0; Ω 1.06 mA, 31; Ω 1.06 mA vs. Ω 1.01 mA, 0 mA vs. 0.2 mA
- 9.93 8
- 9.95 234 mA, 34.9 mA
- 9.99 (I_B, I_C): (a) (135 Ω A, Ω 169 Ω A); (515 Ω A, 0); (169 Ω A, 506 Ω A); (0, 0) (b) all 0 except $I_{B1} = I_{E1} = 203 \Omega$ A
- 9.105 1.85 V, 0.15 V; 62.5 Ω A, Ω 650 Ω A; 13
- 9.107 $Y = \overline{ABC}$; 1.9 V; 0.15 V; 0, Ω 408 Ω A
- 9.109 1.5 V, 0.25 V; 0, Ω 1.00 mA; 16
- 9.111 963 Ω A, 963 Ω A, 0
- 9.116 (I_B, I_C): (532 Ω A, 0); (0, 0); (0, 0); (3.75 Ω A, 150 Ω A)
- 9.120 $Y = A + B + C$; 0 V, Ω 1.0 V; Ω 0.90 V
- 9.121 $Y = A + B + C$; 0 V, Ω 0.80 V; Ω 0.40 V

Chapter 10

10.3 Using MATLAB:

```
t = linspace(0,004);
vs = sin(1000*pi*t)+0.333*sin(3000*pi*t)+0.200*sin(5000*pi*t);
vo= 2*sin(1000*pi*t+pi/6)+sin(3000*pi*t+pi/6)+sin(5000*pi*t+pi/6); plot(t,vs,t,vo)par
500 Hz: 1 0°, 1500 Hz: 0.333 0°, 2500 Hz: 0.200 0°; 2 30°, 1 30° 2 30°, 3 30°, 5 30° yes
```

- 10.5 35.0 dB, 111 dB, 73.2 dB
- 10.8 12.7, 2.00×10^5 , 1.59×10^4
- 10.12 ≈ 10 (20 dB), 0.1 V
- 10.14 $8 \sin(1000t)$; there are only two components; dc: 8 V, 159 Hz: ≈ 4 V
- $$\frac{g_{12}}{g_{11}g_{21}} = \frac{g_{21}}{g_{11}g_{22}}; \frac{g_{22}}{g_{11}} = \frac{g_{12}}{g_{21}} = \frac{1}{g_{22}};$$
- 10.17 11.2%
- 10.21 $10 \text{ k}\Omega$, 1, ≈ 101 , $4.17 \text{ }\Omega$
- 10.23 $24.3 \text{ M}\Omega$, $240 \text{ k}\Omega$, $24.2 \text{ M}\Omega$, $240 \text{ k}\Omega$
- 10.26 $102 \text{ k}\Omega$, 0.0164, 98.3, $16.4 \text{ }\Omega$
- 10.28 $3.50 \text{ k}\Omega$, $1.00 \text{ k}\Omega$, $\approx 6.00 \text{ M}\Omega$, $61.0 \text{ k}\Omega$
- 10.30 1 mS , ≈ 1 , 2001, $20 \text{ k}\Omega$
- 10.32 0.101 S , $50.0 \text{ }\Omega$, $\approx 0.100 \text{ S}$, $50.0 \text{ }\Omega$
- 10.35 $y_{11} = \frac{y_{12}y_{21}}{y_{22}}$; $y_{11} = \frac{y_{12}}{y_{22}} = 0$; $\frac{y_{21}}{y_{22}}$; $\frac{1}{y_{22}}$
- $$\frac{g_{12}}{g_{11}g_{21}} = \frac{g_{21}}{g_{11}g_{22}} = \frac{1}{g_{11}}; \frac{g_{22}}{g_{11}} = \frac{g_{12}}{g_{21}} = 0;$$
- 10.41 45.3 mV; 1.00 W
- 10.45 ≈ 8180
- 10.47 0, , 125 mW,
- 10.50 -3.52 dB, 23.9 kHz
- 10.54 -0.828 dB, 145 Hz
- 10.57 60 dB, 10 kHz, 10 Hz, 9.99 kHz, band-pass amplifier
- 10.59 80 dB, , 50 Hz, , high-pass amplifier
- 10.62 28.3 Hz, 100 kHz
- 10.69 $0.477 \sin(10\sqrt{t} + 63.4^\circ) \text{ V}$, $0.999 \sin(1000\sqrt{t} + 1.72^\circ) \text{ V}$, $0.477 \sin(10^5\sqrt{t} + 78.7^\circ) \text{ V}$
- 10.71 $0.06 \sin(2\sqrt{t} + 88.9^\circ) \text{ V}$, $2.12 \sin(100\sqrt{t} + 45.0^\circ) \text{ V}$, $3.00 \sin(10^4\sqrt{t} + 0.57^\circ) \text{ V}$
- 10.75 $\frac{10^8\sqrt{t}}{s + 10^7\sqrt{t}}$; $\frac{10^8\sqrt{t}}{s + 10^7\sqrt{t}}$
- 10.78 12.8 kHz, -60 dB/decade
- 10.79 $10 \sin(1000\sqrt{t} + 10^\circ) + 3.33 \sin(3000\sqrt{t} + 30^\circ) + 3.00 \sin(5000\sqrt{t} + 50^\circ) \text{ V}$; Using MATLAB:

```
t = linspace(0, 0.004);
vs = sin(1000*pi*t) + 0.333*sin(3000*pi*t) + 0.200*sin(5000*pi*t);
vo = 10*sin(1000*pi*t + pi/18) + 3.33*sin(3000*pi*t + 3*pi/18) + 2.00*sin(5000*pi*t + 5*pi/18);
plot(t, 10*vs, t, vo)
```

Chapter 11

- 11.1 79.9 dB, 120 dB, 89.9 dB; 5.05 mV
- 11.3 $\geq 4.95 \text{ M}\Omega$
- 11.5 0.100 mV, 140 dB
- 11.7 (a) $\approx 46.8, 4.7 \text{ k}\Omega, 0, 33.4 \text{ dB}$
- 11.10 83.9, $\infty, 0, 83.9 \text{ dB}$
- 11.13 $(0.510 \sin 3770t - 1.02 \sin 10000t) \text{ V}, 0$
- 11.15 $\approx 10, 110 \text{ k}\Omega, 10 \text{ k}\Omega$
- 11.18 -12, $(-6 + 1.2\sin 4000\pi t) \text{ V}$
- 11.22 (a) 79.6 pF (b) 82 pF, 19.4 kHz
- 11.26 $\approx 5.00, 20.0 \text{ k}\Omega; +6.00, 27.0 \text{ k}\Omega, 0, 33.0 \text{ k}\Omega$ (not a useful circuit)
- 11.30 0.484 A; 0.730 V; 0.730 V; $\geq 7.03 \text{ W}$ (choose 10 W), 7.27 W
- 11.33 $\frac{v_1 - v_2}{R}; \infty; R(1 + A)$
- 11.35 3.99 V, 3.99 V, 1.99 V, 1.99 V, 3.99 V, 199 μA ; $\approx 5 \text{ M}\Omega$
- 11.37 3.6 $\text{k}\Omega, 49.6 \text{ k}\Omega$
- 11.39 $\approx 1.20 \text{ V}; \approx 1.80 \text{ V}; 0$ to $\approx 3.00 \text{ V}$ in 0.20-V steps
- 11.40 *A* and *B* taken together, *B* and *C* taken together
- 11.43 48.0, $\infty, 0$
- 11.47 -100, 8.62 $\text{k}\Omega, 0$
- 11.50 785 $\text{M}\Omega, 3.75 \text{ m}\Omega$
- 11.56 Noninverting to achieve R_{IN} with an acceptable value for resistor R_2 : R_{OUT} can be met; R_{IN} is not achievable
- 11.58 $\approx 16.2 v_s, 85.9 \text{ m}\Omega$
- 11.60 0.25 percent
- 11.62 60 dB
- 11.67 $0.500 \sin 5000\pi t, 10 \sin 120\pi t; \approx 10, \approx 0.037; 48.6 \text{ dB}; \approx 5.00 \sin 5000\pi t - \approx 0.370 \sin 120\pi t$
- 11.71 $\approx 26.0 \text{ mV}, 0, \approx 26.0 \text{ mV}, \text{yes}, 90.9 \text{ k}\Omega$
- 11.74 $A_V = 10,000 [u(v_{\text{ID}} + 0.0005) - u(v_{\text{ID}} - 0.0015)]$
- 11.76 10.1 $\text{k}\Omega, 1.00 \text{ M}\Omega$
- 11.77 $\approx 0.460 \text{ V}; \approx 0.546 \text{ V}; \approx 18.7 \text{ percent}$
- 11.79 10.0 V, 0 V; 15.0 V, 0.125 V
- 11.81 One possibility: 1 $\text{k}\Omega, 20 \text{ k}\Omega$
- 11.87 $\frac{\Omega}{\Omega} + \frac{R_2}{R_1} \frac{sC(R_1 \parallel R_2) + 1}{sCR_2 + 1}$
- 11.89 3 stages: 1 $\text{k}\Omega, 20 \text{ k}\Omega, 200 \text{ pF}$
- 11.94 $A_V(s) = \frac{3.653 \times 10^{13}}{s^2 + 3.142 \times 10^7 s + 1.916 \times 10^{12}}$; bode ($\approx 3.65e13, [13, 142e7 \ 1.916e12]$)

- 11.97 20 k Ω , 200 k Ω , 796 pF
 11.98 ≈ 20 , 143 kHz; 78.1 dB, 72.9 kHz
 11.101 Two stages
 11.105 6.91, 145 kHz, [6.35, 7.53], [133 kHz, 157 kHz]
 11.107 1.89 V/ μ s
 11.109 10 V/ μ s
 11.110 250 k Ω , 1 k Ω , 2.55 μ F, 8 $\times 10^4$, 50 μ s; add two $10^9 \mu$ F resistors
 11.116 200,000, $10^{12} \mu$ s, 1 k Ω , unspecified, 12.7 μ F
 11.118 0.010 μ F, 0.005 μ F, 1.13 k Ω , 20.0 kHz; 0.005 μ F, 0.0025 μ F

Chapter 12

- 12.1 (a) 0.005 μ F, 0.01 μ F, 1.13k Ω , 1, 20 kHz
 12.5
$$\frac{K}{s^2 R_1 R_2 C_1 C_2 + s[R_1 C_1(1 - K) + C_2(R_1 + R_2)] + 1}; \frac{K}{3 - K}$$

 12.7 ≈ 1 ; ≈ 1
 12.11 1 k Ω , 100 k Ω , 0.0159 μ F
 12.13 1 rad/s, 0.0640 rad/s, 15.6; $\frac{20}{s^2 + 0.1s + 1}$
 12.15 5.48 kHz, 1.34 kHz, 4.05, 63.1 dB
 12.18 0
 12.21 (0, $T/2$): 0 V, ($T/2, 3T/2$): 1 V, ($3T/2, 5T/2$): 4 V, ($5T/2, 7T/2$): 8 V, ($7T/2, 9T/2$): 12 V, ($9T/2, 5T$): 15 V
 12.24 12.6 kHz, 1.58, 7.96 kHz
 12.27 ≈ 1.125 V; ≈ 1.688 V; $n \approx (\approx 0.1875)$ V
 12.30 000: 0, 001: 0.1220, 010: 0.2564, 100: 0.5000; 0.0716 LSB, 0.0434 LSB; 0.376 LSB, 0.188 LSB
 12.33 1.43 percent, 2.5 percent, 5 percent, 10 percent
 12.35 ≈ 0.3125 V, ≈ 0.6250 V, ≈ 1.250 V, ≈ 2.500 V
 12.37 1.0742 k Ω , 0.188 LSB, 0.094 LSB; 1.2929 k Ω , 0.224 LSB, 0.417 LSB
 12.40 (a) $(2^{n+1}-1)C$ (b) $(3n+1)C$
 12.43 ≈ 2.500 V, ≈ 1.875 V, ≈ 1.250 V, ≈ 0.625 V, 0 V, +0.625 V, 1.250 V, +1.875 V
 12.45 (3.415468 V, 3.415781 V)
 12.49 0001011111, 95 μ s
 12.51 167 ns
 12.53 $RC \geq 0.0448$ s; $v_o(200 \text{ ms}) = 22.32$ V
 12.55 For $\phi = 0$, $\frac{V_M T_T}{RC} \frac{\sin \phi T_T}{\phi T_T}$
 12.57 $\approx V_1 V_2 / (10^4 I_s)$

- 12.59 0.759 V
- 12.60 2.40 Hz
- 12.65 2.38 V, 2.62 V, 0.240 V
- 12.67 0.487 V, $\square 0.487$ V, 0.974 V
- 12.70 0 Hz
- 12.73 841 \square s, 416 \square s

Chapter 13

- 13.1 $0.700 + 0.005 \sin 2000 \square t$ V; $1.03 \sin 2000 \square t$ V; $5.00 \square 1.03 \sin 2000 \square t$ V; 2.82 mA
- 13.3 Bypass, coupling, coupling; 0 V
- 13.6 Coupling, bypass, coupling; 0 V
- 13.9 Coupling, coupling, coupling
- 13.12 Coupling, coupling
- 13.14 (1.78 mA, 6.08 V)
- 13.16 (98.4 \square A, 4.96 V)
- 13.20 (82.2 \square A, 6.04 V)
- 13.24 (307 \square A, 3.88 V)
- 13.28 (338 \square A, 5.40 V)
- 13.32 (1.00 mA, 7.50 V)
- 13.42 Thévenin equivalent source resistance, gate-bias voltage divider, gate-bias voltage divider, source-bias resistor—sets source current, drain-bias resistor—sets drain-source voltage, load resistor
- 13.45 11.3 \square A, 50 mV
- 13.48 (188 \square A, $V_{CE} \geq 0.7$ V), 7.52 mS, 532 k \square
- 13.51 (1.88 \square A, $V_{CE} \geq 0.7$ V), 75.0 \square S, 53.3 M \square
- 13.53 (b) +16.7%, -13.6%
- 13.54 90, 120; 95, 75
- 13.58 $\square 120$
- 13.60 Yes, using $I_{CR_C} = (V_{CC} + V_{CE})/2$
- 13.62 2.5 mA; 30.7 V
- 13.64 $\square 314$, $\square 314$
- 13.66 $\square 95$
- 13.67 ($\square 95.0$, $\square 94.1$)
- 13.71 3
- 13.74 1.25 A
- 13.77 10%, 20%
- 13.80 Virtually any desired Q-point
- 13.81 (156 \square A, 9 V)

- 13.87 $400 = 133,000i_P + v_{PK}$; (1.4 mA, 215 V); 1.6 mS, 55.6 k Ω , 89, ≈ 62.7
- 13.88 FET
- 13.91 111 μ A, 1400
- 13.94 Yes, it is possible although the required value of $V_{GS} \approx V_{TN}$ (6.70 V) is getting rather large
- 13.97 0.5 V, (125 μ A, 7.5 V)
- 13.98 2.5 V, 25 V
- 13.100 3
- 13.102 ≈ 10.9
- 13.105 ≈ 7.27
- 13.110 833 μ A
- 13.112 33.3 k Ω , 94.4 k Ω
- 13.115 647 Ω , 3.62 k Ω
- 13.116 (b) 1 M Ω , 0, ≈ 7.45 M Ω , 3.53 M Ω
- 13.118 6.8 M Ω , 45.8 k Ω
- 13.120 10 M Ω , 508 k Ω
- 13.122 1 M Ω , 6.82 k Ω
- 13.125 ≈ 15.0 v_s, 45.8 k Ω
- 13.129 ≈ 60.7 , 630 Ω , 960 Ω ; gain reduced by 25 percent due to lower input resistance
- 13.131 62.9 k Ω , 96.0 k Ω , -64.4
- 13.133 50 mA/V², 842 k Ω
- 13.139 1.38 μ W, 0.581 mW, 0.960 mW, 0.887 mW, 2.43 mW
- 13.143 0.497 mW, 0.554 mW, 2.07 mW, 24.6 μ W, 24.6 μ W, 5.58 mW
- 13.146 $V_{CC}/15$
- 13.147 3.38 V, 13.6 V
- 13.150 32.9 μ A, 2.30 V
- 13.152 356 μ A, 2.02 V
- 13.153 500 μ A, 1.76 V

Chapter 14

- 14.1 (a) C-C, (b) not useful, (h) C-B, (o) C-D
- 14.8 ≈ 5.00 , , 20.0 k Ω , ; ≈ 10.0 , , 10.0 k Ω ,
- 14.10 (a) ≈ 6.91 (e) ≈ 120
- 14.11 6.58 k Ω , 66.7 k Ω
- 14.16 ≈ 120 , ≈ 60.9 , 2.83 k Ω , 8.20 k Ω , 6.76 mV
- 14.17 ≈ 14.7 , ≈ 11.6 , 368 k Ω , 75 k Ω , 183 mV
- 14.19 ≈ 3.07 , 84.9, 1.00 M Ω , 39.0 k Ω , 1.49 V
- 14.24 0.909, , 100 Ω ,

- 14.27 0.982, 1.29, 31.6 k Ω , 9.19 Ω , 2.83 V
- 14.28 0.956, 969, 1.00 M Ω , 555 Ω , 628 V
- 14.30 $(0.005 + 0.2 V_{R4})$ V
- 14.33 48.8, 2.00 k Ω , , 1; 14.3, 2.00 k Ω , , 1
- 14.34 48.8, 1.98 k Ω , 4.92 M Ω , 1; 23.7, 1.98 k Ω , 10.1 M Ω , 1
- 14.38 5.51, 0.178, 2.73 k Ω , 24.0 k Ω , 0.398 V
- 14.39 36.5, 0.274, 252 Ω , 39.0 k Ω , 14.9 mV
- 14.43 44.5 Ω
- 14.45 632 Ω
- 14.47 $(\beta_o + 1)r_o = 153$ M Ω
- 14.48 $A_v = 398$ with $R_{in} = 1$ M Ω : A C-E amplifier operating at low current should be able to achieve both high A_v and high R_{in} . It would be difficult to achieve $A_v = 52$ dB with an FET stage.
- 14.51 A follower has a gain of approximately 0 dB. The input resistance of a C-C amplifier is approximately $(\beta_o + 1)R_L \approx 101(10$ k $\Omega) = 1$ M Ω . Therefore a C-D stage would be preferred to achieve the gain of approximately 1 with $R_{in} = 25$ M Ω .
- 14.52 A noninverting amplifier is needed. Either the C-B or C-G amplifier should be able to achieve $A_v = +10$ with $R_{in} = 2$ k Ω with proper choice of the Q-point.
- 14.55 1.66 Ω
- 14.59 $\beta_f v_s, R_5 + r_o(1 + g_m R_5) \approx r_o(1 + g_m R_5)$
- 14.61 $v_s, (R_{th} + r_{\pi})/(\beta_o + 1)$
- 14.63 (a) $z_{21} = R_B \frac{(\beta_o + 1)R_E}{r_{\pi} + (\beta_o + 1)R_E} \approx R_B$ $z_{12} = \frac{R_B R_E}{R_B + r_{\pi} + (\beta_o + 1)R_E} \approx \frac{R_B}{(\beta_o + 1)}$ $\frac{z_{21}}{z_{12}} \approx \beta_o + 1$
- 14.65 (a) $g_{21} = +g_m R_D$ $g_{12} = \frac{R_D}{R_D + r_o} \approx \frac{R_D}{r_o}$ $\frac{g_{21}}{g_{12}} \approx g_m r_o = \beta_f$
- 14.68 $(1/g_m)(1 + R_L/r_o)$ for $\beta_f \gg 1$
- 14.69 $\approx 0.984, 0.993, 0.703$ V
- 14.72 SPICE: (106 μ A, 7.14 V), $\approx 14.2, 369$ k Ω , 65.8 k Ω
- 14.74 SPICE: (9.81 μ A, 5.74 V), 0.983, 11.0 M Ω , 2.58 k Ω
- 14.78 SPICE: (268 μ A, 8.60 V), 4.26, 1.27 k Ω , 18.8 k Ω
- 14.79 SPICE: (5.59 mA, 5.93 V), $\approx 3.27, 10.0$ M Ω , 1.53 k Ω
- 14.81 SPICE: (3.84 mA, 10.0 V), 0.953, 1.00 M Ω , 504 Ω
- 14.83 (a) 0.01 μ F, 270 μ F, 0.15 μ F, (b) 2.7 μ F
- 14.86 (a) 0.50 μ F, 0.68 μ F
- 14.89 (a) 8200 pF, 820 pF (b) 0.042 μ F, 1800 pf, 0.015 μ F
- 14.91 33.3 mA
- 14.93 $R_1 = 120$ k Ω , $R_2 = 110$ k Ω

14.95 The second MOSFET

14.97 $A_v^{\max} = 54.8$, $A_v^{\min} = 44.8$ beyond the Monte Carlo results by approximately 2 percent of nominal gain.

14.101 Voltage is not sufficient—transistor will be saturated.

14.105 95.2, 1000 Ω , 1; A_v is 2 Ω larger, R_{in} is 2 Ω smaller

Chapter 15

15.1 4.12, 1 M Ω , 64.3 Ω

15.2 4.44

15.5 2.19

15.7 711, 8.29 k Ω , 401 Ω

15.10 466, 73.8 k Ω , 20 k Ω

15.16 (a) (5.00 mA, 10.3 V), (1.88 mA, 3.21 V), (2.47 mA, 6.86 V) (b) (5.00 mA, 9.45 V), (2.38 mA, 0.108 V), (3.15 mA, 4.60 V) Q_2 is saturated! The circuit will no longer function properly as an amplifier.

15.17 (a) (325 μ A, 7.14 V), (184 μ A, 7.85 V), 86.1 dB

15.20 (a) (50.0 μ A, 1.58 V), (215 μ A, 13.2 V), β 63.2, 1 M Ω , 1.91 k Ω

15.22 (a) (223 μ A, 2.87 V), (1.96 mA, 5.00 V), β 218, 7.61 k Ω , 241 Ω (b) β 1.49, 75.6 k Ω

15.25 (a) (4.44 μ A, 1.40 V), (23.3 μ A, 2.30 V) (b) (4.08 μ A, 1.42 V), (23.6 μ A, 2.28 V)

15.27 4.05 M Ω , 2.00 mS, 553 k Ω , 77.2 pS

15.30 3.28 M Ω , 2.50 mS, 640 k Ω , 8190, 1600

15.35 $I_{C2} = \beta_F I_{C1}$, $g_m = g_m$, $r_{\pi} = \beta_o r_{\pi}$, $r_d = \frac{r_o}{2}$, $\beta_{\text{eff}} = \beta_o(\beta_o + 1)$, $\beta_{\text{eff}} = \frac{\beta_f}{2}$

15.38 $I_{C2} = \beta_F I_{C1}$, $g_m = g_m$, $r_{\pi} = \beta_o r_{\pi}$, $r_d = r_o \beta_o$, $\beta_{\text{eff}} = \beta_f$

15.42 (8.52 μ A, 1.42 V), (8.40 μ A, 0.940 V), β 48.1, cascode amplifier

15.43 (a) (20.7 μ A, 5.87 V) (b) β 273, 243 k Ω , 660 k Ω (c) β 0.604, 47.1 dB, 27.3 M Ω

15.46 (a) (8.43 μ A, 1.36 V) (b) β 33.7, β 1.02 k Ω , for differential output, 24.4 dB for single-ended output, 594 k Ω , 200 k Ω , 4.90 M Ω , 50 k Ω

15.48 $R_{EE} = 1.1$ M Ω , $R_C = 1.0$ M Ω

15.50 (200 μ A, 4.90 V); differential output: β 312, 0, ; single-ended output: β 155, β 0.0965, 64.2 dB; 25.0 k Ω , 40.4 M Ω , 78.0 k Ω , 39.0 k Ω

15.52 1.00 μ A, 2.02 μ A, 2.50 G Ω

15.54 $V_O = 1.09$ V, $v_o = 0$; $V_O = 1.09$ V, $v_o = 219$ mV; 5.00 mV

15.56 (47.4 μ A, 6.23 V); Differential output: β 379, 0, ; single-ended output: β 190, β 0.661, 49.2 dB; 158 k Ω , 22.7 M Ω

15.60 β 16.1 V, β 13.1 V, β 3.00 V

15.61 β 283, 4.94 $\times 10^3$, 95.2 dB

- 15.66** (24.2 μ A, 5.36 V); $A_{dd} = 45.9$, $A_{cc} = 0.738$, differential CMRR = , single-ended CMRR = 24.7 dB, ,
- 15.69** (91.3 μ A, 12.9 V); $A_{dd} = 16.7$, $A_{cc} = 0.486$, differential CMRR = , single-ended CMRR = 25.1 dB, ,
- 15.74** (150 μ A, 7.60 V); $A_{dd} = 26$, $A_{cc} = 0.233$, differential CMRR = , single-ended CMRR = 34.9 dB, ,
- 15.77** (142 μ A, 7.27 V); $A_{dd} = 21.7$, $A_{cc} = 0.785$, differential CMRR = , single-ended CMRR = 22.9 dB, ,
- 15.79** (20.0 μ A, 6.67 V); $A_{dd} = 26.8$, $A_{cc} = 0.119$, differential CMRR = , single-ended CMRR = 41.0 dB, ,
- 15.80** 3.08 V, 1.22 V, 62.1 mV
- 15.83** (99.0 μ A, 10.8 V); $A_{dd} = 30.1$, $A_{cc} = 0.165$, 553 k Ω
- 15.86** (400 μ A, 1.71 V), (100 μ A, -2.82 V), -26.8, 0, ∞
- 15.88** (24.8 μ A, 12.0 V), (500 μ A, 12.0 V), 1040, 202 k Ω , 20.6 k Ω , 147 M Ω , v_1
- 15.92** (a) (98.8 μ A, 14.3 V), (300 μ A, 14.3 V) (b) 551, 40.5 k Ω , (c) 49.0 k Ω (d) 34.6 M Ω , (e) v_2
- 15.97** (98.8 μ A, 14.3 V), (300 μ A, 14.3 V), 27800, 40.5 k Ω
- 15.102** (a) (250 μ A, 15.6 V), (500 μ A, 15.0 V) (b) 4300, , 165 k Ω (c) v_2 (d) v_1
- 15.107** (250 μ A, 4.92 V), (6.10 μ A, 4.30 V), (494 μ A, 5.00 V), 4230, , 97.5 k Ω
- 15.109** (b-e) 12100, 101 k Ω , 180 k Ω , 66.3 M Ω , v_2
- 15.113** (250 μ A, 10.9 V), (2.00 mA, 9.84 V), (5.00 mA, 12.0 V), 866, , 127 Ω
- 15.115** (300 μ A, 5.10 V), (500 μ A, 2.89 V), (2.00 mA, 5.00 V), 529, , 341 Ω
- 15.120** (99.0 μ A, 5.00 V), (500 μ A, 3.41 V), (2.00 mA, 5.00 V), 11400, 50.5 k Ω , 224 Ω
- 15.121** (4.95 μ A, 2.36 V), (24.5 μ A, 3.07 V), (245 μ A, 3.00 V), 249, 1.01 M Ω , 1.63 k Ω , v_B , v_A , 900, r_{π} and r_{π}^t are low, R_{IN5} is low.
- 15.123** (99.0 μ A, 1.40 V), (990 μ A, 12.0 V), 189, 50.6 k Ω , 1.06 k Ω
- 15.127** (24.8 μ A, 17.3 V), (24.8 μ A, 17.3 V), (9.62 μ A, 15.9 V), (490 μ A, 16.6 V), (49.0 μ A, 17.3 V), (4.95 mA, 18.0 V), 88.5 dB, 202 k Ω , 18.1 Ω
- 15.129** 36.8 μ A
- 15.131** 196 μ A
- 15.135** 22.8 μ A
- 15.137** 5 mA, 0 mA, 10 mA, 12.5 percent
- 15.138** 100 percent
- 15.141** 70 mA, 19.6 V
- 15.144** 6.98 mA, 0 mA
- 15.145** 25.0 m Ω
- 15.147** (a) 22.8 μ A, 43.9 M Ω
- 15.151** Two of many: 75 k Ω , 62 k Ω , 150 Ω ; 68 k Ω , 12 k Ω , 1 k Ω
- 15.155** 96.7 μ A, 16.3 M Ω

- 15.158** 20.2 μA , 101 M Ω
15.164 16.9 μA , 168 M Ω , 5.11 μA , 555 M Ω , 16.9 μA , 168 M Ω
15.166 44.1 μA , 22.1 M Ω , 10.0 μA , 210 M Ω
15.170 100 μA , 657 G Ω
15.171 (9.34 μA , 9.03 V), (4.62 μA , 7.62 V), 96.5 dB
15.173 $\omega_1 \omega_{f1} / 2$
15.174 3.16 V

Chapter 16

- 16.1** 4.06 k Ω \parallel R \parallel 4.31 k Ω
16.4 19.8 percent, 13.3 percent
16.6 7.69 percent, 0.813 μA , 0.855 μA
16.11 274 μA , 383 k Ω , 574 μA , 192 k Ω
16.16 (a) 944 μA , 68.9 k Ω , 1.52 mA, 41.5 k Ω
16.18 458 k Ω , 103 μA , 541 k Ω , 103 μA
16.20 185 μA , 299 μA
16.24 125 μA , 690 μA , 1.31 mA, 600 k Ω , 100 k Ω , 66.4 k Ω
16.27 10
16.31 15.7 μA , 5.10 M Ω
16.34 12.3 μA , 31.3 M Ω , 29.3 μA , 15.2 M Ω
16.38 172 k Ω , 9.78 k Ω , 0.445
16.42 $-V_{EE} + 1.16 \text{ V}$ for $V_{CB3} \geq 0$
16.47 $-V_{EE} + 1.91 = -8.09 \text{ V}$
16.48 3.80/1
16.50 17.5 μA , 1.16 G Ω ; 20.3 kV; 2.11 V
16.52 5%, 0
16.55 16.9 μA , 163 M Ω , 2750 V; $2V_{BE} = 1.4 \text{ V}$
16.57 3.80/1
16.59 127 μA , 1.89 M Ω , 129 μA , 1.97 M Ω
16.62 8.22 k Ω
16.65 318 μA , 295 μA , 66.5 μA
16.68 187 μA
16.72 46.5 μA , 140 μA
16.75 $n > 1/3$
16.77 26.4 μA
16.82 30.7 μA , 15.3 μA
16.85 462 μA , 308 μA

- 16.88 1.172 V, 307K
 16.91 44.0 $\mu\text{V/K}$
 16.94 2.293 k Ω , 10.47 k Ω
 16.96 79.1, 6.28×10^{-5} , 122 dB
 16.100 1200, 0, , 2.9 V
 16.104 (100 μA , 8.70 V), (100 μA , 7.45 V), (100 μA , 2.50 V), (100 μA , 1.25 V), 323, 152
 16.106 (125 μA , 1.54 V), (125 μA , 2.79 V), (125 μA , 2.50 V), (125 μA , 1.25 V); 19600
 16.109 171 μA
 16.110 (b) 100 μA
 16.111 (125 μA , 8.63 V), (125 μA , 1.31 V), (125 μA , 10.0 V), (125 μA , 8.71 V), (125 μA , 1.29 V),
 (125 μA , 6.00 V), (125 μA , 2.75 V); 43.4; 14,900
 16.113 10,800
 16.118 6400; 80,000
 16.119 7500; 7500
 16.122 7.78, 574 Ω , 3.03×10^5 , 60.0 k Ω
 16.124 ± 1.4 V, ± 2.4 V
 16.127 271 k Ω , 255 Ω
 16.129 $V_{EE} \geq 2.8$ V, $V_{CC} \geq 1.4$ V; 3.8 V, 1.7 V
 16.130 0.406 mS, 2.83 M Ω
 16.134 (100 μA , 15.7 V), (50 μA , 12.9 V), (50 μA , 0.700 V), (50 μA , 1.40 V), (50 μA , 29.3 V), (100
 μA , 0.700 V), (100 μA , 13.6 V), 1 mS, 752 k Ω
 16.136 (25 μA , 2.50 V), (50 μA , 3.20 V)
 16.137 (a) 125 μA , 75 μA , 62.5 μA , 37.5 μA (b) 125 μA , 0, 75 μA (c) 125 μA , 0, 75 μA

Chapter 17

- 17.1 $25, \frac{s^2}{(s+1)(s+20)}$, yes, $\frac{25s}{(s+20)}$, 3.18 Hz, 3.19 Hz
 17.4 $200, \frac{1}{\frac{\square}{\square} + \frac{s \square}{10^4 \square} + \frac{s \square}{10^5 \square}}$ yes, 1.59 kHz, 1.58 kHz
 17.7 $200, \frac{s^2}{(s+1)(s+2)}$, $\frac{1}{\frac{\square}{\square} + \frac{s \square}{500 \square} + \frac{s \square}{1000 \square}}$, .356 Hz, 71.2 Hz; 0.380 Hz, 66.7 Hz
 17.10 (b) $\square 14.1$ (23.0 dB), 11.8 Hz
 17.12 19.3 dB, 151 Hz; 35.0 dB, 12.6 Hz
 17.21 7.24 dB, 19.2 Hz
 17.23 0.964, 0.627 Hz

- 17.24 0.152 μF
- 17.27 Cannot reach 1 Hz; $f_L = 13.1$ Hz for $C_1 =$, limited by C_3
- 17.29 0.351 μF
- 17.31 308 ps
- 17.34 μ100 ; μ107
- 17.36 0.977; 0.978
- 17.37 μ5100 , $\mu\text{98.0}$, μ5000 , μ100 ; μ350 , $\mu\text{42.9}$, μ300 , μ50
- 17.40 $\mu\text{98.7}$, 1.42 MHz
- 17.46 μ129 , 1.10 MHz
- 17.50 $1/10^5 RC$; $1/10^6 RC$; $1/sRC$
- 17.52 $(2750 \mu j4.99) \mu$, $(2730 \mu j226) \mu$, $(836 \mu j1040) \mu$
- 17.58 $\mu\text{9.44}$, 43.9 Hz, 9.02 MHz; 85.1 MHz
- 17.62 μ1300 ; $\mu\text{92.3}$; μ100 , μ1200
- 17.63 9.13, 40.9 MHz
- 17.66 2.30, 10.9 MHz
- 17.71 0.964, 114 MHz
- 17.73 $C_{GD} + C_{GS}/(1 + g_m R_L)$ for $\mu \ll \mu_T$
- 17.76 99.3 kHz
- 17.77 48.2 kHz
- 17.87 4 GHz, 39.8 ps
- 17.90 781 μA
- 17.91 8.33 MHz
- 17.95 10.6 MHz, 33.3 V/ms
- 17.100 8 V/ μs
- 17.104 22.5 MHz, 2.91, $\mu\text{41.1}$
- 17.105 20.1 pF, 12.6, $n = 2.81$, 21.9 pF
- 17.107 15.2 MHz; 27.5 MHz
- 17.108 13.4 MHz, 7.98, $112/\mu\text{90}^\circ$; 4.74 MHz, 5.21, $46.1/\mu\text{90}^\circ$
- 17.113 10.9 MHz, 16.4, $\mu\text{75.1}$; 10.1 MHz, 3.96, $\mu\text{35.4}$

Chapter 18

- 18.5 $1/(1+A\mu)$; $9.99 \mu 10^{\text{dB}}$ percent
- 18.8 100 dB
- 18.13 800 M μ ; 2.00 μ ; 20.0 M μ ; 50 m μ
- 18.15 18.8 k μ , 1.02 mS, $\mu\text{75.0} \mu 10^3$, 3141, 0.0993, 10.0; 0.0993 @ 0; 75,000 @ 0.0993
- 18.17 0.999, 43.9 M μ , 2.49 μ , 98.9 ms
- 18.20 $A\mu/(1 + A\mu)$; 99.9 percent
- 18.22 $\mu\text{33.0 k}$; 8.11 k μ ; 0.705 μ

- 18.23 82.2 Ω ; 46.2 Ω ; 32.4 k Ω ; 32.4
- 18.24 36.8 Ω ; 18.6 Ω ; 34.4 k Ω
- 18.26 0.973, 973 Ω
- 18.29 446 k Ω , 50.4 k Ω , 2.45 k Ω
- 18.31 11.0, 15.2 Ω , 2.72 M Ω
- 18.32 21.9 Ω ; 12.3 Ω ; 35.1
- 18.37 $\beta_o/(\beta_o + 1)$, $2/g_m$, $(\beta_o + 1)r_o$
- 18.40 58.2 dB
- 18.43 91.8
- 18.45 $(s/R_2C_2)/[s^2 + s(1/R_2C_2 + 1/(R_1||R_2)C_1) + 1/R_1R_2C_1C_2]$
- 18.50 $T_V = 987$, $T_I = 110$, $T = 98.5$
- 18.59 114 dB, 0 Hz, 1000 Hz, 0 Hz, 101 kHz
- 18.62 46.1 kHz, 9.31 Hz, 81.0 kHz, 5.29 Hz
- 18.69 110 kHz; A \approx 2000; larger
- 18.71 yes, but almost no phase margin; 1.83°
- 18.73 90.0°
- 18.75 12°; yes
- 18.81 phase margin is undefined; $|T(j\Omega)| < 1$ for all Ω
- 18.85 38.4°
- 18.86 $\beta = 1/RC$, $R_F = 2R$
- 18.88 63.7 kHz, 6.85 V
- 18.90 18.4 kHz, 10.7 V
- 18.95 9.00 MHz, 1.20
- 18.101 11.2 MHz, 18.1 MHz, 1.00
- 18.102 15.9155 mH, 15.9155 fF; 10.008 MHz, 10.003 MHz
- 18.103 9.190 MHz; 9.190 MHz